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View Online at https://aerobasegroup.com/nsn/5962-01-370-2940 **Body Length:** 0.560 inches **Body Width:** Between 0.442 inches and 0.458 inches **Body Height:** Between 0.060 inches and 0.120 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Burn in and monolithic and programmable **Inclosure Material:** Ceramic **Inclosure Configuration:** Leadless flat pack **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 24 input **Case Outline Source And Designator:** C-12 mil-m-38510 **Current Rating Per Characteristic:** 125.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.5 volts power source and 7.0 volts power source **Memory Device Type:** Ram **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 32 leadless Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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